MIC33050

4 MHz Internal Inductor PWM Buck Power Module with HyperLight Load®

Features

- · Input Voltage: 2.7V to 5.5V
- · 600 mA Output Current
- · Fixed and Adjustable Output Voltage Options
- · No External Inductor Required
- · Ultra-Fast Transient Response
- · 20 µA Quiescent Current
- · 4 MHz Switching in PWM Mode
- · Low Output Voltage Ripple
- >93% Peak Efficiency
- >85% Efficiency at 1 mA
- · Micropower Shutdown
- 12-Pin 3 mm x 3 mm HDFN
- –40°C to +125°C Junction Temperature Range

Applications

- MPU Power
- · Portable Instrumentation
- · Wearable Devices
- · Space-Constrained MCU Systems
- · RF Modules
- · USB-Powered Devices

General Description

The MIC33050 is a high-efficiency 600 mA PWM synchronous buck (step-down) regulator with internal inductor featuring HyperLight Load[®], a switching scheme that offers best-in-class light load efficiency and transient performance while providing very small external components and low output ripple at all loads.

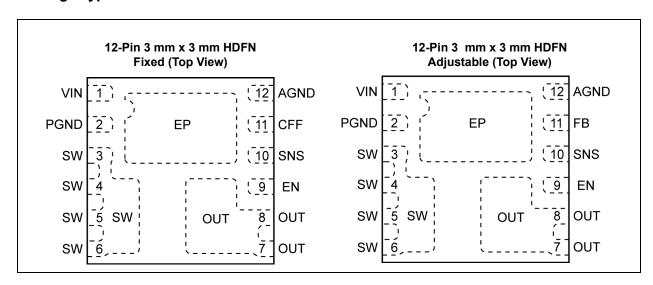
The MIC33050 also has a very low typical quiescent current of 20 μA and can achieve over 85% efficiency even at 1 mA.

In contrast to traditional light load schemes, the HyperLight Load[®] architecture does not trade off control speed to obtain low standby currents and in doing so, the device only needs a small output capacitor to absorb the load transient as the powered device goes from light load to full load.

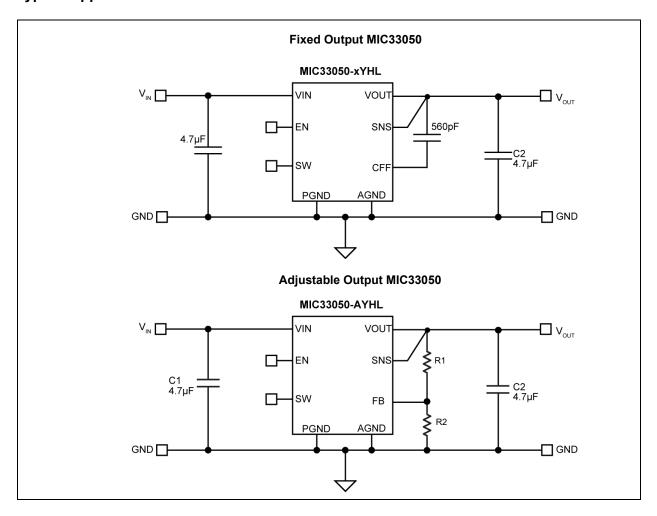
At higher loads, the MIC33050 provides a nearly constant switching frequency of greater than 4 MHz while providing peak efficiencies greater than 93%.

The MIC33050 is available in fixed and adjustable output voltages and comes in a 12-pin 3 mm x 3 mm HDFN with a operating junction temperature range of -40° C to $+125^{\circ}$ C.

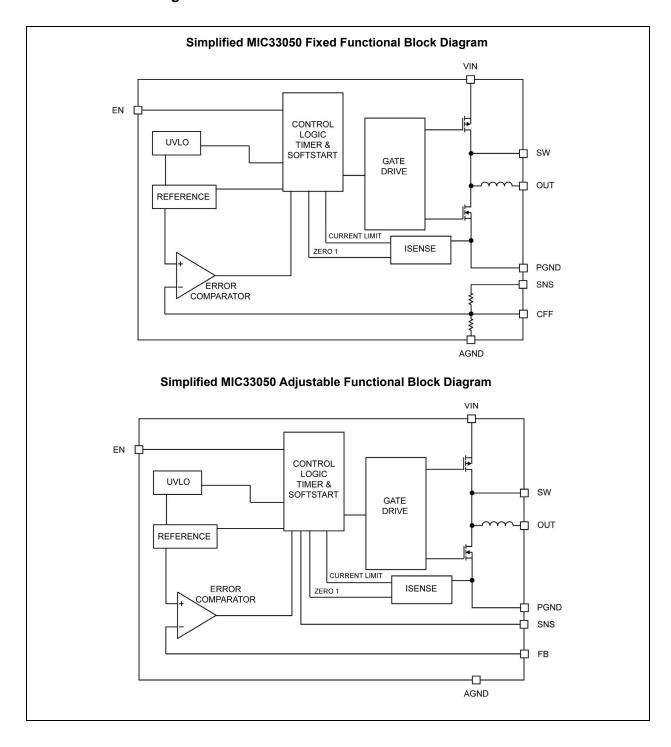
Package Types



Typical Application Circuits



Functional Block Diagrams



1.0 **ELECTRICAL CHARACTERISTICS**

Absolute Maximum Ratings †

Operating Patings +	
ESD Rating (Note 1)	ESD Sensitive
Logic Enable Input Voltage (V _{EN})	
Output Switch Current (I _{SW})	2A
Output Switch Voltage (V _{SW})	+6V
Supply Voltage (V _{IN})	+6V

Operating Ratings ‡

Supply Voltage (V_{IN}).....+2.7V to +5.5V

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability. Specifications are for packaged product only.

‡ Notice: The device is not guaranteed to function outside its operating ratings.

Note 1: Devices are ESD sensitive. Handling precautions are recommended. Human body model, 1.5 kΩ in series with 100 pF.

ELECTRICAL CHARACTERISTICS

 $\textbf{Electrical Characteristics:} \ T_{A} = 25^{\circ}\text{C}, \ V_{IN} = V_{EN} = 3.6\text{V}; \ C_{FF} = 560 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ C_{OUT} = 4.7\mu\text{F}; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} = 20 \ mA \ unless = 1.00 \ pF; \ I_{OUT} =$ otherwise specified. **Bold** values indicate -40° C $\leq T_{J} \leq +125^{\circ}$ C. Specification for packaged product only.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Supply Voltage Range	V _{IN}	2.7	_	5.5	V	_
Undervoltage Lockout Threshold	UVLO	2.45	2.55	2.65	٧	Turn-On
Undervoltage Lockout Hysteresis	UVLO _{HYS}	_	100	_	mV	_
Quiescent Current	IQ	_	20	32	μA	$I_{OUT} = 0$ mA, SNS > 1.2 * $V_{OUT(NOM)}$
Shutdown Current	I _{SHDN}	_	0.01	4	μA	$V_{EN} = 0V; V_{IN} = 5.5V$
Output Voltage Accuracy	ΔV _{OUT}	-2.5	_	+2.5	%	V_{IN} = 3.0V; I_{LOAD} = 20 mA
Current Limit in PWM Mode	I _{LIM}	0.65	1	1.7	Α	$V_{SNS} = 0.9*V_{OUT(NOM)}$
Output Voltage Line Regulation	ΔV _{O_LINE}	_	0.5	_	%/V	V _{IN} = 3.0V to 5.5V, I _{LOAD} = 20 mA
Output Voltage Load Regulation	ΔV_{O_LOAD}	_	0.3	_	%	20 mA < I _{LOAD} < 500 mA
Feedback Voltage	V_{FB}	390	400	410	mV	V _{IN} = 3.0V; I _{OUT} = 20 mA
Maximum Duty Cycle	D _{MAX}	80	89	_	%	V _{SNS} ≤ V _{OUT(NOM)}
PWM Switch On-Resistance	R _{DS(ON)P}	_	0.45		Ω	I _{SW} = 100 mA PMOS
	R _{DS(ON)N}	_	0.5	_	1 12	I _{SW} = -100 mA NMOS
Switching Frequency	f _{SW}	_	4		MHz	I _{OUT} = 120 mA
Soft Start Time	t _{SS}	—	650		μs	$V_{OUT} = 90\%$ of $V_{OUT(NOM)}$
Enable Threshold	V _{ENTH}	0.5	0.8	1.2	V	Turn-On
Enable Hysteresis	V _{ENHYS}	_	35	_	mV	_
Enable Input Current	I _{EN}	_	0.1	2	μA	_
Overtemperature Shutdown	T _{SD}	_	165		°C	_
Overtemperature Shutdown Hysteresis	T _{SDHYS}	_	20	_	°C	_

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Operating Junction Temperature Range	T_J	-40	_	+125	°C	_
Storage Temperature Range	T _S	-65	_	+150	°C	_
Package Thermal Resistances						
Thermal Resistance 12-Pin HDFN 3 mm x 3 mm	θ_{JA}	_	60	_	°C/W	_

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

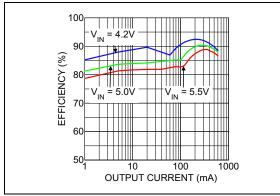


FIGURE 2-1: Efficiency ($V_{OUT} = 3.3V$).

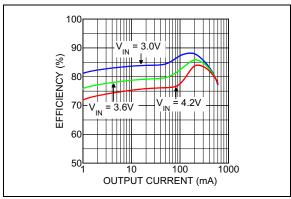


FIGURE 2-2: Efficiency $(V_{OUT} = 1.8V)$.

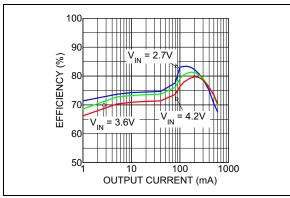


FIGURE 2-3: Efficiency $(V_{OUT} = 1.2V)$.

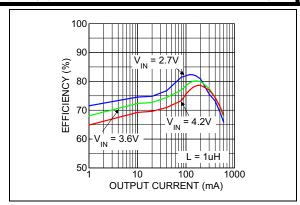


FIGURE 2-4: Efficiency $(V_{OUT} = 1.0V)$.

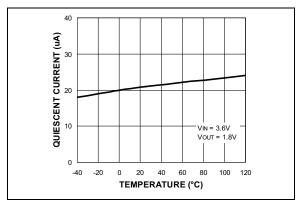


FIGURE 2-5: Quiescent Current vs. Temperature.

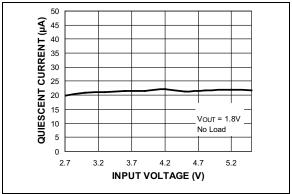


FIGURE 2-6: Quiescent Current vs. Input Voltage.

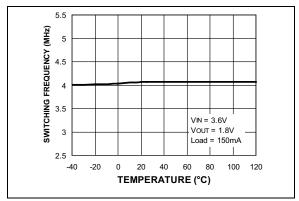


FIGURE 2-7: Switching Frequency vs. Temperature.

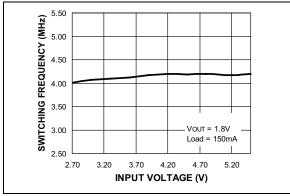


FIGURE 2-8: Switching Frequency vs. Input Voltage.

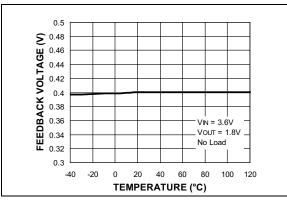


FIGURE 2-9: Feedback Voltage vs. Temperature.

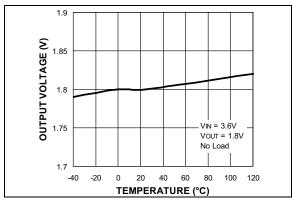


FIGURE 2-10: Output Voltage vs. Temperature.

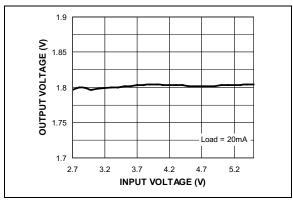


FIGURE 2-11: Output Voltage vs. Input Voltage.

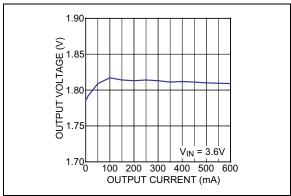


FIGURE 2-12: Output Voltage vs. Output Current.

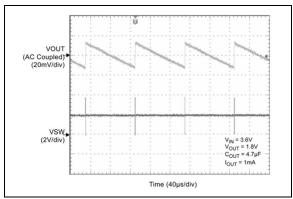


FIGURE 2-13: Switching Waveforms, $(I_{OUT} = 1 \text{ mA}).$

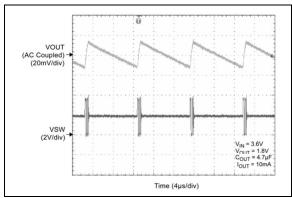


FIGURE 2-14: Switching Waveforms, $(I_{OUT} = 10 \text{ mA}).$

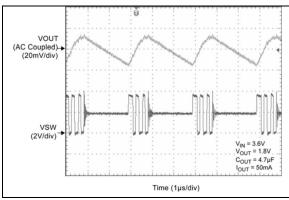


FIGURE 2-15: Switching Waveforms, $(I_{OUT} = 50 \text{ mA}).$

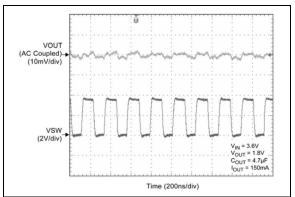


FIGURE 2-16: Switching Waveforms, $(I_{OUT} = 150 \text{ mA}).$

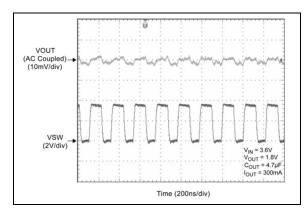


FIGURE 2-17: Switching Waveforms, $(I_{OUT} = 300 \text{ mA}).$

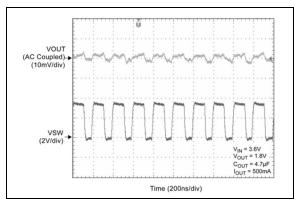


FIGURE 2-18: Switching Waveforms, $(I_{OUT} = 500 \text{ mA}).$

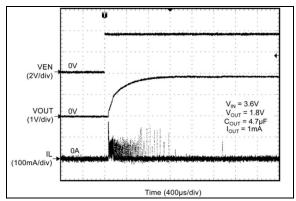


FIGURE 2-19:

Start-Up, $(I_{OUT} = 1 mA)$.

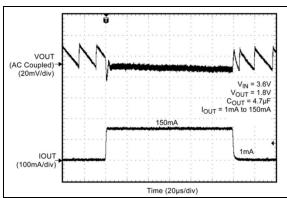


FIGURE 2-20: Load Transient, (1 mA to 150 mA).

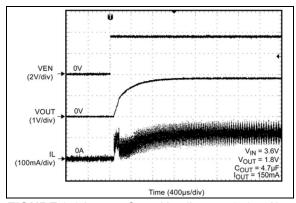


FIGURE 2-21:

Start-Up, $(I_{OUT} = 150 \text{ mA})$.

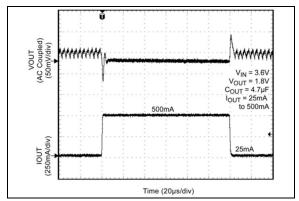


FIGURE 2-22: 500 mA).

Load Transient, (25 mA to

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin Number MIC33050 (Fixed Option)	Pin Number MIC33050 (Adj. Option)	Pin Name	Description
1	1	VIN	Supply Voltage (Input): Requires bypass capacitor to GND.
2	2	PGND	Power Ground.
3, 4, 5, 6	3, 4, 5, 6	SW	Switch (Output): Internal power MOSFET output switches.
7, 8	7, 8	OUT	Output after the internal inductor.
9	9	EN	Enable (Input): Logic low will shut down the device, reducing the quiescent current to less than 4 µA. Do not leave floating.
10	10	SNS	Input to the error amplifier. Connect to the external resistor divider network to see the output voltage. For fixed output voltages connect V _{OUT} (internal resistor network sets the output voltage).
11	_	CFF	Feed forward capacitor connected to out sense pin.
	11	FB	Feedback voltage. Connect a resistor divider from output to ground to set the output voltage.
12	12	AGND	Analog ground.
ePAD	ePAD	ePAD	Exposed Heatsink Pad. Connect to power ground for best thermal performance.

4.0 FUNCTIONAL DESCRIPTION

4.1 VIN

VIN provides power to the MOSFETs for the switch mode regulator section and to the analog supply circuitry. Due to the high switching speeds, it is recommended that a 2.2 μF or greater capacitor be placed close to VIN and the power ground (PGND) pin for bypassing.

4.2 EN

The enable pin, EN, controls the on and off state of the device. A high logic on the enable pin activates the regulator while a low logic deactivates it. MIC33050 features built-in soft-start circuitry that reduces in-rush current and prevents the output voltage from overshooting at start-up. Do not leave floating.

4.3 SW

The pins at the switch node, SW, are connected directly to the internal inductor. Due to the high-speed switching on this pin, the switch node should be routed away from sensitive nodes such as the CFF and FB pins.

4.4 OUT

The OUT pin is for the output voltage following the internal inductor of the device. Connect an output filter capacitor equal to 2.2 µF or greater to this pin.

4.5 SNS

The sense pin, SNS, is needed to sense the output voltage at the output filter capacitor. In order for the control loop to monitor the output voltage accurately it is good practice to sense the output voltage at the positive side of the output filter capacitor where voltage ripple is smallest.

4.6 CFF

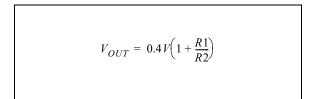
The CFF pin is connected to the SNS pin of MIC33050 with a feed-forward capacitor of 560 pF. The CFF pin itself is compared with the internal reference voltage (V_{REF}) of the device and provides the control path to control the output. V_{REF} is equal to 400 mV. The CFF pin is sensitive to noise and should be place away from the SW pin.

4.7 FB

The feedback pin is provided for the adjustable output version. An external resistor divider network is connected from the output and is compared to the internal 400 mV internal reference voltage within the control loop.

The output voltage, of the circuit in Figure 4-1, may be calculated via the equation below:

EQUATION 4-1:



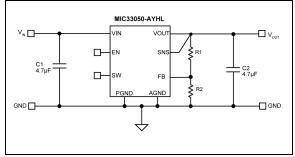


FIGURE 4-1: MIC33050-AYHL Application Schematic.

4.8 PGND

Power ground (PGND) is the ground path for high current. The current loop for the power ground should be as small as possible and separate from the analog ground (AGND) loop.

4.9 AGND

Signal ground (AGND) is the ground path for the biasing and control circuitry. The current loop for the signal ground should be separate from the PGND loop.

5.0 APPLICATIONS INFORMATION

5.1 Input Capacitor

A minimum of $2.2 \,\mu\text{F}$ ceramic capacitor should be placed close to the VIN pin and PGND pin for bypassing. X5R or X7R dielectrics are recommended for the input capacitor. Y5V dielectrics, aside from losing most of their capacitance over temperature, they also become resistive at high frequencies. This reduces their ability to filter out high frequency noise.

5.2 Output Capacitor

The MIC33050 was designed for use with a $2.2~\mu F$ or greater ceramic output capacitor. A low equivalent series resistance (ESR) ceramic output capacitor either X7R or X5R is recommended. Y5V and Z5U dielectric capacitors, aside from the undesirable effect of their wide variation in capacitance over temperature, become resistive at high frequencies.

5.3 Compensation

The MIC33050 is designed to be stable with an internal inductor with a minimum of 2.2 μF ceramic (X5R) output capacitor.

5.4 Efficiency Considerations

Efficiency is defined as the amount of useful output power, divided by the amount of power supplied.

EQUATION 5-1:

$$\eta = \left(\frac{V_{OUT} \times I_{OUT}}{V_{IN} \times I_{IN}}\right) \times 100$$

Maintaining high efficiency serves two purposes. It reduces power dissipation in the power supply, reducing the need for heat sinks and thermal design considerations and it reduces consumption of current for battery powered applications. Reduced current draw from a battery increases the devices operating time which is critical in hand held devices.

There are two types of losses in switching converters; DC losses and switching losses. DC losses are simply the power dissipation of $\rm l^2R$. Power is dissipated in the high-side switch during the on cycle. Power loss is equal to the high-side MOSFET $\rm R_{DS(ON)}$ multiplied by the switch current squared. During the off cycle, the low-side N-channel MOSFET conducts, also dissipating power. Device operating current also reduces efficiency. The product of the quiescent (operating) current and the supply voltage represents another DC loss. The current required driving the gates on and off at a constant 4 MHz frequency and the switching transitions make up the switching losses.

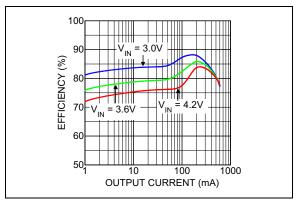


FIGURE 5-1: Efficiency under Load.

Figure 5-1 shows an efficiency curve. From 1 μ A to 100 mA, efficiency losses are dominated by quiescent current losses, gate drive and transition losses. By using the HyperLight Load[®] mode, the MIC33050 is able to maintain high efficiency at low output currents.

Over 100 mA, efficiency loss is dominated by MOSFET $R_{DS(ON)}$ and inductor losses. Higher input supply voltages will increase the gate to source threshold on the internal MOSFETs, thereby reducing the internal $R_{DS(ON)}$. This improves efficiency by reducing DC losses in the device. All but the inductor losses are inherent to the device. In which case, inductor selection becomes increasingly critical in efficiency calculations. As the inductors are reduced in size, the DC resistance (DCR) can become quite significant.

The DCR losses can be calculated by using Equation 5-2:

EQUATION 5-2:

$$P_{D(L)} \approx I_{OUT}^2 \times DCR$$

From that, the loss in efficiency due to inductor resistance can be calculated by using Equation 5-3:

EQUATION 5-3:

$$EfficiencyLoss = \left[1 - \left(\frac{V_{OUT} \times I_{OUT}}{V_{OUT} \times I_{OUT} + P_{D(L)}}\right)\right] \times 100$$

Efficiency loss due to DCR is minimal at light loads and gains significance as the load is increased. Inductor selection becomes a trade-off between efficiency and size in this case.

5.5 HyperLight Load[®] Mode

The MIC33050 uses a minimum on and off time proprietary control loop. When the output voltage falls below the regulation threshold, the error comparator begins a switching cycle that turns the PMOS on and keeps it on for the duration of the minimum on-time. When the output voltage is over the regulation threshold, the error comparator turns the PMOS off for a minimum off-time. The NMOS acts as an ideal rectifier that conducts when the PMOS is off. Using a NMOS switch instead of a diode allows for lower voltage drop across the switching device when it is on. The asynchronous switching combination between the PMOS and the NMOS allows the control loop to work in discontinuous mode for light load operations. In discontinuous mode, MIC33050 works in pulse frequency modulation (PFM) to regulate the output. As the output current increases, the switching frequency increases. This improves the efficiency of the MIC33050 during light load currents. As the load current increases, the MIC33050 goes into continuous conduction mode (CCM) at a constant frequency of 4 MHz. The equation to calculate the load when the MIC33050 goes into continuous conduction mode may be approximated by the following Equation 5-4:

EQUATION 5-4:

$$I_{LOAD} = \left(\frac{(V_{IN} - V_{OUT}) \times D}{2L \times f}\right)$$

6.0 PACKAGING INFORMATION

6.1 Package Marking Information

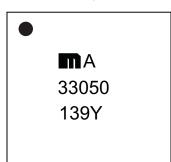
Legend:

XX...X





Example



Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')
NNN Alphanumeric traceability code

(e3) Pb-free JEDEC® designator for Matte Tin (Sn)

Product code or customer-specific information

This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

•, ▲, ▼ Pin one index is identified by a dot, delta up, or delta down (triangle mark).

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

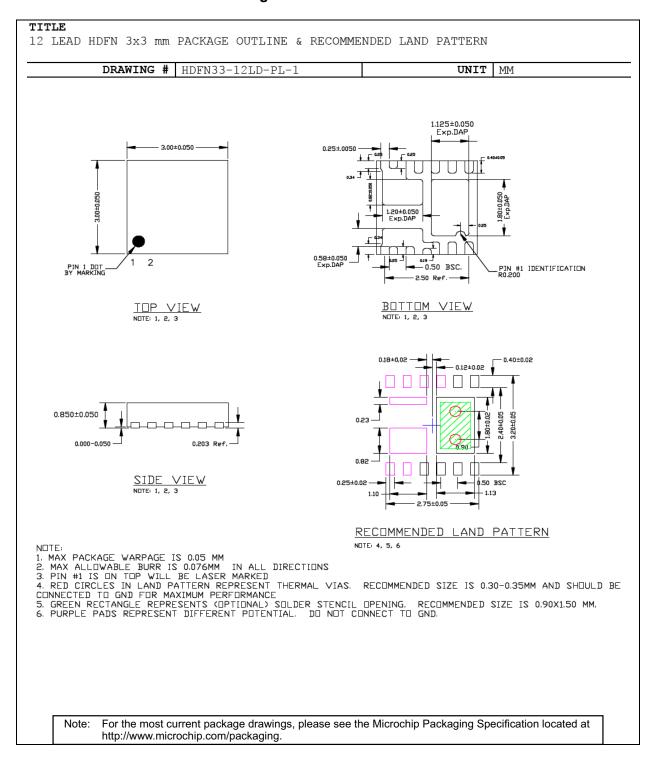
Underbar (_) and/or Overbar (_) symbol may not be to scale.

Note: If the full seven-character YYWWNNN code cannot fit on the package, the following truncated codes are used based on the available marking space:

6 Characters = YWWNNN; 5 Characters = WWNNN; 4 Characters = WNNN; 3 Characters = NNN;

2 Characters = NN; 1 Character = N

12-Lead HDFN 3 mm x 3 mm Package Outline and Recommended Land Pattern





NOTES:

APPENDIX A: REVISION HISTORY

Revision A (November 2018)

- Converted Micrel document MIC33050 to Microchip data sheet DS20006120B.
- · Minor text changes throughout.
- Deleted bullet: Up to 8 MHz PWM Operation in Continuous Mode from the Features, Updated Applications, removed the word patent-pending from General Description, Revised Figure 2-6 and Figure 2-8.

Revision B (March 2022)

- Corrected package marking drawings and added note below legend in Section 6.1, Package Marking Information.
- · Minor formatting corrections throughout.



NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO. <u>-X</u> Device Output **Package** Junction Media Type Voltage Temperature Option Range

MIC33050: 4 MHz Internal Inductor PWM Buck Power Device:

Module with HyperLight Load

C = 1.0V4 = 1.2V

Output Voltage: G = 1.8V S = 3.3V

A = Adjustable

Junction

-40°C to +125°C (Pb-Free, RoHS Compliant) Temperature Range:

Package: HL = 12-Lead 3 mm x 3 mm x 0.9 mm HDFN

Media Type: = 500/Reel T5 TR = 5000/Reel

Note: Other output voltage options are available. Contact Factory for details.

Examples:

a) MIC33050-4YHL-TR: 4 MHz Internal Inductor PWM Buck

Power Module with HyperLight Load®, 1.2V Fixed Output Voltage, –40°C to +125°C Junction Temperature Range, Pb-Free, RoHS Compliant, 12-Lead HDFN

Package, 5000/Reel

b) MIC33050-GYHL-TR: 4 MHz Internal Inductor PWM Buck Power Module with HyperLight

Load[®], 1.8V Fixed Output Voltage, –40°C to +125°C Junction Temperature Range, Pb-Free, RoHS Compliant, 12-Lead HDFN Package, 5000/Reel

c) MIC33050-SYHL-TR: 4 MHz Internal Inductor PWM Buck Power Module with HyperLight

Load®, 3.3V Fixed Output Voltage, -40°C to +125°C Junction Temperature Range, Pb-Free, RoHS Compliant, 12-Lead HDFN

Package, 5000/Reel

d) MIC33030-AYHL-T5: 4 MHz Internal Inductor PWM Buck

Power Module with HyperLight Load[®], Adjustable Output Voltage, -40°C to +125°C Junction Temperature Range, Pb-Free RoHS Compliant, 12-Lead HDFN

Package, 500/Reel

e) MIC33030-AYHL-TR: 4 MHz Internal Inductor PWM Buck

Power Module with HyperLight Load[®], Adjustable Output Voltage, –40°C to +125°C Junction Temperature Range, Pb-Free, RoHS Compliant, 12-Lead HDFN

Package, 5000/Reel

Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on

the device package. Check with your Microchip Sales Office for package availability with the

Tape and Reel option.



NOTES:

Note the following details of the code protection feature on Microchip products:

- Microchip products meet the specifications contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is secure when used in the intended manner, within operating specifications, and under normal conditions
- Microchip values and aggressively protects its intellectual property rights. Attempts to breach the code protection features of Microchip product is strictly prohibited and may violate the Digital Millennium Copyright Act.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of its code. Code protection does not
 mean that we are guaranteeing the product is "unbreakable". Code protection is constantly evolving. Microchip is committed to
 continuously improving the code protection features of our products.

This publication and the information herein may be used only with Microchip products, including to design, test, and integrate Microchip products with your application. Use of this information in any other manner violates these terms. Information regarding device applications is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. Contact your local Microchip sales office for additional support or, obtain additional support at https://www.microchip.com/en-us/support/design-help/client-support-services.

THIS INFORMATION IS PROVIDED BY MICROCHIP "AS IS". MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION INCLUDING BUT NOT LIMITED TO ANY IMPLIED WARRANTIES OF NON-INFRINGEMENT, MERCHANTABILITY, AND FITNESS FOR A PARTICULAR PURPOSE, OR WARRANTIES RELATED TO ITS CONDITION, QUALITY, OR PERFORMANCE.

IN NO EVENT WILL MICROCHIP BE LIABLE FOR ANY INDIRECT, SPECIAL, PUNITIVE, INCIDENTAL, OR CONSEQUENTIAL LOSS, DAMAGE, COST, OR EXPENSE OF ANY KIND WHATSOEVER RELATED TO THE INFORMATION OR ITS USE, HOWEVER CAUSED, EVEN IF MICROCHIP HAS BEEN ADVISED OF THE POSSIBILITY OR THE DAMAGES ARE FORESEEABLE. TO THE FULLEST EXTENT ALLOWED BY LAW, MICROCHIP'S TOTAL LIABILITY ON ALL CLAIMS IN ANY WAY RELATED TO THE INFORMATION OR ITS USE WILL NOT EXCEED THE AMOUNT OF FEES, IF ANY, THAT YOU HAVE PAID DIRECTLY TO MICROCHIP FOR THE INFORMATION.

Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

For information regarding Microchip's Quality Management Systems, please visit www.microchip.com/quality.

Trademarks

The Microchip name and logo, the Microchip logo, Adaptec, AnyRate, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, CryptoMemory, CryptoRF, dsPIC, flexPWR, HELDO, IGLOO, JukeBlox, KeeLoq, Kleer, LANCheck, LinkMD, maXStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

AgileSwitch, APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, Flashtec, Hyper Speed Control, HyperLight Load, IntelliMOS, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet-Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, TrueTime, WinPath, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, Augmented Switching, BlueSky, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, Espresso T1S, EtherGREEN, GridTime, IdealBridge, In-Circuit Serial Programming, ICSP, INICnet, Intelligent Paralleling, Inter-Chip Connectivity, JitterBlocker, Knob-on-Display, maxCrypto, maxView, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, NVM Express, NVMe, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, RTAX, RTG4, SAM-ICE, Serial Quad I/O, simpleMAP, SimpliPHY, SmartBuffer, SmartHLS, SMART-I.S., storClad, SQI, SuperSwitcher, SuperSwitcher II, Switchtec, SynchroPHY, Total Endurance, TSHARC, USBCheck, VariSense, VectorBlox, VeriPHY, ViewSpan, WiperLock, XpressConnect, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

 $\ensuremath{\mathsf{SQTP}}$ is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, Symmcom, and Trusted Time are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2018 - 2022, Microchip Technology Incorporated and its subsidiaries.

All Rights Reserved.

ISBN: 978-1-6683-0158-6



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200

Fax: 480-792-7277 Technical Support:

http://www.microchip.com/ support

Web Address:

www.microchip.com

Atlanta Duluth, GA

Tel: 678-957-9614 Fax: 678-957-1455

Austin, TX Tel: 512-257-3370

Boston

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Novi, MI

Tel: 248-848-4000

Houston, TX

Tel: 281-894-5983 Indianapolis

Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453 Tel: 317-536-2380

Los Angeles

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608 Tel: 951-273-7800

Raleigh, NC Tel: 919-844-7510

New York, NY Tel: 631-435-6000

San Jose, CA Tel: 408-735-9110 Tel: 408-436-4270

Canada - Toronto Tel: 905-695-1980 Fax: 905-695-2078

ASIA/PACIFIC

Australia - Sydney Tel: 61-2-9868-6733

China - Beijing Tel: 86-10-8569-7000

China - Chengdu Tel: 86-28-8665-5511

China - Chongqing Tel: 86-23-8980-9588

China - Dongguan Tel: 86-769-8702-9880

China - Guangzhou Tel: 86-20-8755-8029

China - Hangzhou Tel: 86-571-8792-8115

China - Hong Kong SAR Tel: 852-2943-5100

China - Nanjing Tel: 86-25-8473-2460

China - Qingdao Tel: 86-532-8502-7355

China - Shanghai

Tel: 86-21-3326-8000 China - Shenyang

Tel: 86-24-2334-2829

China - Shenzhen Tel: 86-755-8864-2200

China - Suzhou Tel: 86-186-6233-1526

China - Wuhan Tel: 86-27-5980-5300

China - Xian

Tel: 86-29-8833-7252 China - Xiamen

Tel: 86-592-2388138 **China - Zhuhai** Tel: 86-756-3210040

ASIA/PACIFIC

India - Bangalore Tel: 91-80-3090-4444

India - New Delhi Tel: 91-11-4160-8631

India - Pune Tel: 91-20-4121-0141

Japan - Osaka Tel: 81-6-6152-7160

Japan - Tokyo

Tel: 81-3-6880- 3770

Korea - Daegu Tel: 82-53-744-4301

Korea - Seoul Tel: 82-2-554-7200

Malaysia - Kuala Lumpur Tel: 60-3-7651-7906

Malaysia - Penang Tel: 60-4-227-8870

Philippines - Manila Tel: 63-2-634-9065

Singapore Tel: 65-6334-8870

Taiwan - Hsin Chu Tel: 886-3-577-8366

Taiwan - Kaohsiung Tel: 886-7-213-7830

Taiwan - Taipei Tel: 886-2-2508-8600

Thailand - Bangkok Tel: 66-2-694-1351

Vietnam - Ho Chi Minh Tel: 84-28-5448-2100

EUROPE

Austria - Wels Tel: 43-7242-2244-39 Fax: 43-7242-2244-393

Denmark - Copenhagen Tel: 45-4485-5910 Fax: 45-4485-2829

Finland - Espoo Tel: 358-9-4520-820

France - Paris
Tel: 33-1-69-53-63-20
Fax: 33-1-69-30-90-79

Germany - Garching Tel: 49-8931-9700

Germany - Haan Tel: 49-2129-3766400

Germany - Heilbronn Tel: 49-7131-72400

Germany - Karlsruhe Tel: 49-721-625370

Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Germany - Rosenheim Tel: 49-8031-354-560

Israel - Ra'anana Tel: 972-9-744-7705

Italy - Milan Tel: 39-0331-742611 Fax: 39-0331-466781

Italy - Padova Tel: 39-049-7625286

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

Norway - Trondheim Tel: 47-7288-4388

Poland - Warsaw Tel: 48-22-3325737

Romania - Bucharest Tel: 40-21-407-87-50

Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Gothenberg Tel: 46-31-704-60-40

Sweden - Stockholm Tel: 46-8-5090-4654

UK - Wokingham Tel: 44-118-921-5800 Fax: 44-118-921-5820